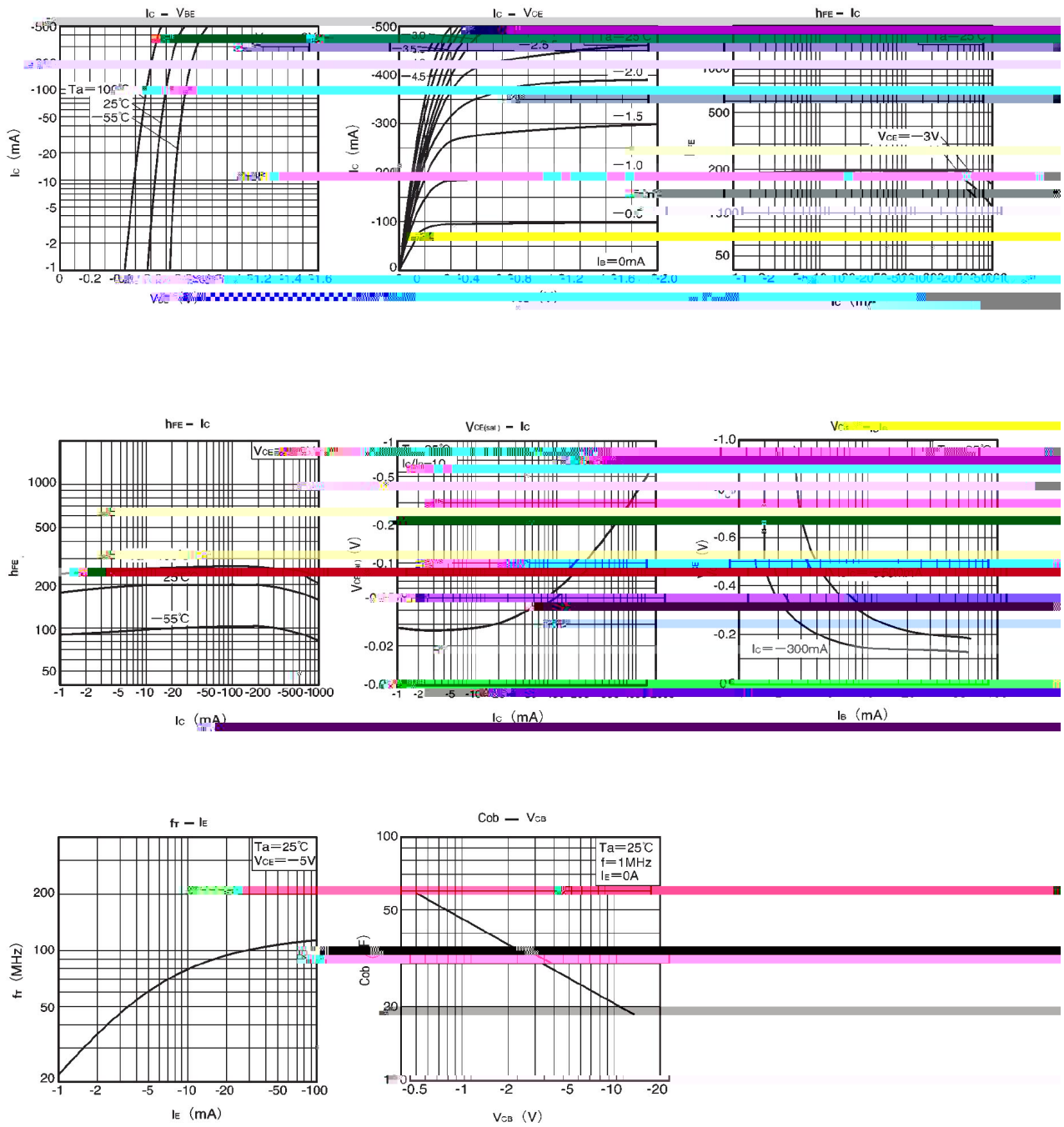


WR0<50 P ММ Ё SQS æ Ñ ç s ll 1 Silicon PNP transistor in a TO-92LM Plastic Package.

т = я ъ Н/л 5VG4;8; Й ´
Low saturation voltage, complements the 2SD1858.

т = я ъ Н/л 5VG4;8; Й ´
tTT2 -7 4Dø-7 17(.00018 Tc.224 (Silicoymbol(w)9ans/TT2 45 71TD-.574(kD001 Tc4.002)9a254(k)TjP Q Ma8)-6Rs

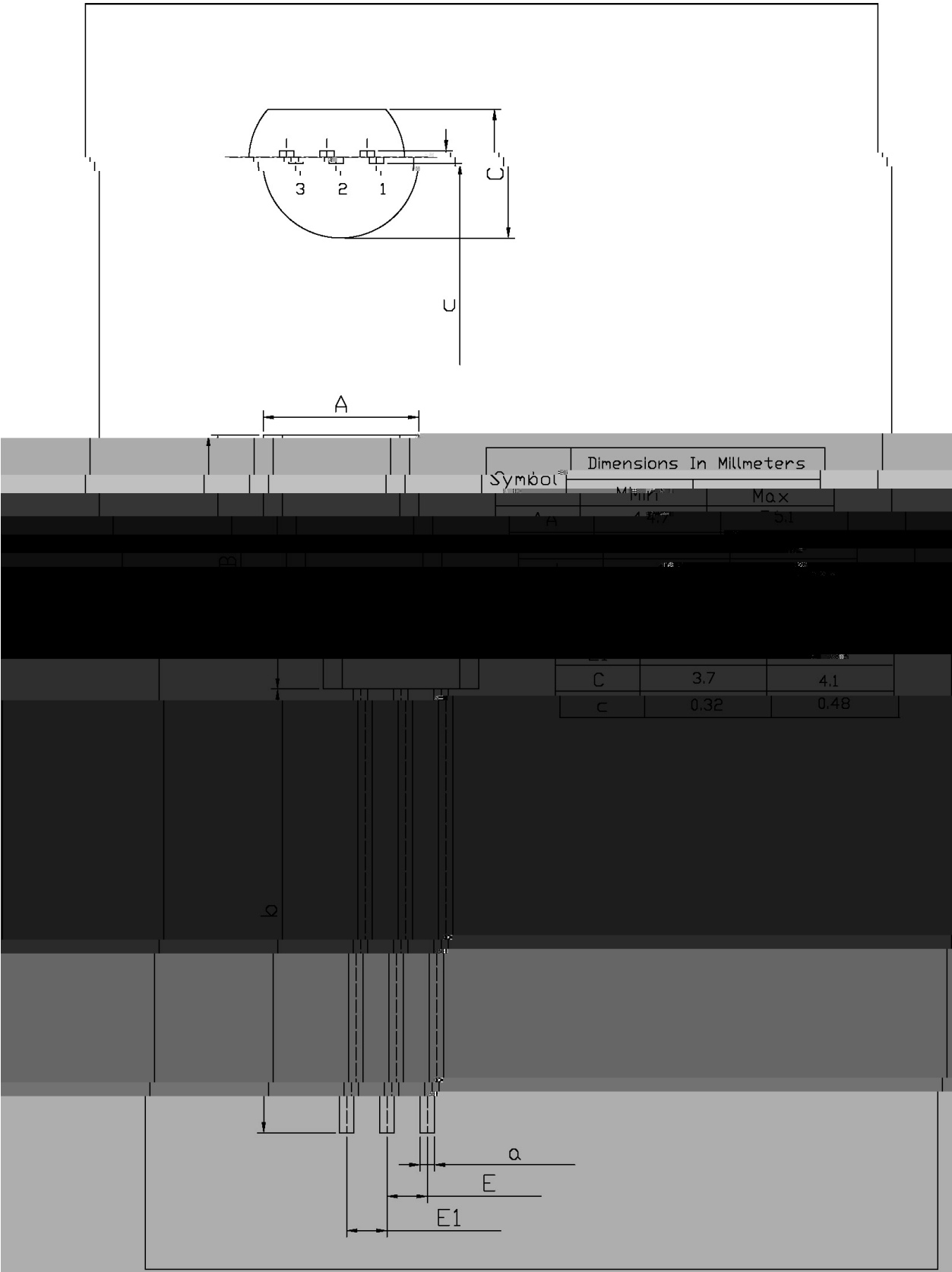
/ Electrical Characteristic Curve



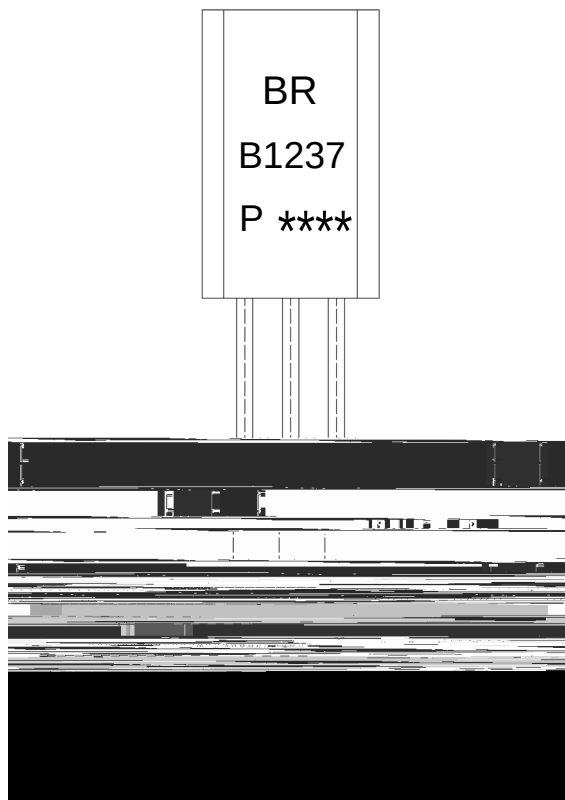
/ Package Dimensions

TO-92LM

Unit: mm



/ Marking Instructions



б " X

EU: ㄣ 3 ㄴ ㄱ

E456: X ㄣ 3 ㄴ ㄱ

S: ㄣ k_{IH} ' 6 ㄱ

---- X ㄣ 1 F ㄴ ㄴ ㄱ 1 ㄱ 1 F ㄴ ㄴ ㄱ

Note:

BR: Company Code.

B1237: Product Type.

P: h_{FE} Classifications Symbol

****: Lot No. Code,code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



б " X

1. 1. Preheating: 25~150 °C, Time: 60~90sec;
2. 2. Peak Temp.: 255 °C, Duration: 5 ° 0.5sec;
3. 3. Cooling Speed: 2~10 ° /sec.

Note:

1. Preheating: 25~150 °C, Time: 60~90sec.
2. Peak Temp.: 255 °C, Duration: 5 ° 0.5sec.
3. Cooling Speed: 2~10 ° /sec.

/ Resistance to Soldering Heat Test Conditions

□ °C 270 ± 5 °C, Time: 10 ± 1 sec. Temp.: 270 ± 5 °C Time: 10 ± 1 sec

/ Packaging SPEC.

“Q” T Y E / BULK

Package Type	Units					Dimension (unit mm3)		
	Units/Bag	Bags/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Bag	Inner Box	Outer Box
TO-92LM	1,000	8	8,000	5	40,000	135×190	237×172×102	560×245×195

“A” V Y E / AMMO

Package Type	Units					Dimension (unit mm3)	
	Units/tape	Tape/Inner Box	Rows/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Inner Box	Outer Box
TO-92LM	2,500	1	100	10	25,000	328×230×42	480×346×235 547×407×268

/ Notices